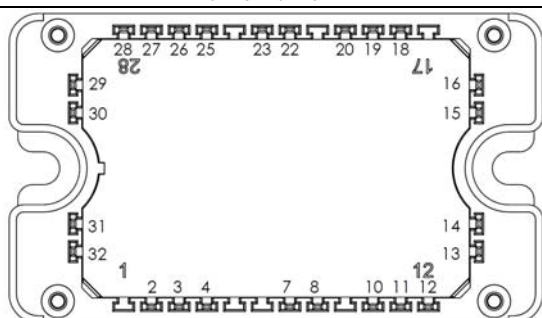
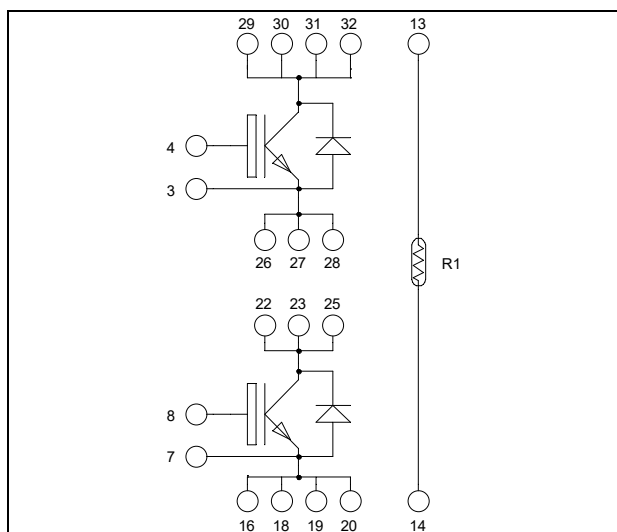


Phase leg Trench + Field Stop IGBT3 Power Module

$V_{CES} = 1200V$
 $I_C = 150A @ T_c = 100^\circ C$



Pins 29/30/31/32 must be shorted together
 Pins 26/27/28/22/23/25 must be shorted together
 to achieve a phase leg
 Pins 16/18/19/20 must be shorted together

All ratings @ $T_j = 25^\circ C$ unless otherwise specified

Absolute maximum ratings (Per IGBT)

Symbol	Parameter	Max ratings	Unit
V_{CES}	Collector - Emitter Voltage	1200	V
I_C	Continuous Collector Current	$T_C = 25^\circ C$	220
		$T_C = 100^\circ C$	150
I_{CM}	Pulsed Collector Current	$T_C = 25^\circ C$	300
V_{GE}	Gate - Emitter Voltage	± 20	V
P_D	Power Dissipation	$T_C = 25^\circ C$	833
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^\circ C$	300A @ 1150V

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- **Trench + Field Stop IGBT3**
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Low leakage current
 - RBSOA and SCSOA rated
- Very low stray inductance
- Kelvin emitter for easy drive
- Internal thermistor for temperature monitoring
- AlN substrate for improved thermal performance

Benefits

- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Electrical Characteristics (Per IGBT)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$			250	μA
$V_{CE(sat)}$	Collector Emitter Saturation Voltage	$V_{GE} = 15V$ $I_C = 150A$		$T_j = 25^\circ C$ 1.7 $T_j = 125^\circ C$ 2.0	2.1	V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 3mA$	5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$			400	nA

Dynamic Characteristics (Per IGBT)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{ies}	Input Capacitance	$V_{GE} = 0V$		10.7		nF
C_{oes}	Output Capacitance	$V_{CE} = 25V$		0.56		
C_{res}	Reverse Transfer Capacitance	$f = 1MHz$		0.48		
Q_G	Gate charge	$V_{GE} = \pm 15V; V_{CE} = 600V$ $I_C = 150A$		1.4		μC
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching ($25^\circ C$) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_C = 150A$ $R_G = 2.2\Omega$		280		ns
T_r	Rise Time			40		
$T_{d(off)}$	Turn-off Delay Time			420		
T_f	Fall Time			75		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching ($125^\circ C$) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_C = 150A$ $R_G = 2.2\Omega$		290		ns
T_r	Rise Time			45		
$T_{d(off)}$	Turn-off Delay Time			520		
T_f	Fall Time			90		
E_{on}	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_C = 150A$		14		mJ
E_{off}	Turn-off Switching Energy	$R_G = 2.2\Omega$ $T_j = 125^\circ C$		16		
I_{sc}	Short Circuit data	$V_{GE} \leq 15V; V_{Bus} = 900V$ $t_p \leq 10\mu s; T_j = 125^\circ C$		600		A
R_{thJC}	Junction to Case Thermal Resistance				0.15	$^\circ C/W$

Reverse diode ratings and characteristics (Per diode)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
V_{RRM}	Peak Repetitive Reverse Voltage				1200	V
I_{RM}	Reverse Leakage Current	$V_R = 1200V$			350	μA
I_F	DC Forward Current	$T_c = 80^\circ C$		150		A
V_F	Diode Forward Voltage	$I_F = 150A$ $V_{GE} = 0V$		$T_j = 25^\circ C$ 1.6 $T_j = 125^\circ C$ 1.6	2.1	V
t_{rr}	Reverse Recovery Time	$I_F = 150A$ $V_R = 600V$ $di/dt = 2500A/\mu s$		$T_j = 25^\circ C$ 170 $T_j = 125^\circ C$ 280		ns
Q_{rr}	Reverse Recovery Charge			$T_j = 25^\circ C$ 14 $T_j = 125^\circ C$ 28		
E_r	Reverse Recovery Energy			$T_j = 25^\circ C$ 6 $T_j = 125^\circ C$ 11		mJ
R_{thJC}	Junction to Case Thermal Resistance				0.25	$^\circ C/W$

Thermal and package characteristics

Symbol	Characteristic	Min	Max	Unit
V _{ISOL}	RMS Isolation Voltage, any terminal to case t=1 min, 50/60Hz	4000		V
T _J	Operating junction temperature range	-40	150	°C
T _{JOP}	Recommended junction temperature under switching conditions	-40	T _{Jmax} -25	
T _{STG}	Storage Temperature Range	-40	125	
T _C	Operating Case Temperature	-40	125	
Torque	Mounting torque	To heatsink	M4	N.m
Wt	Package Weight		110	g

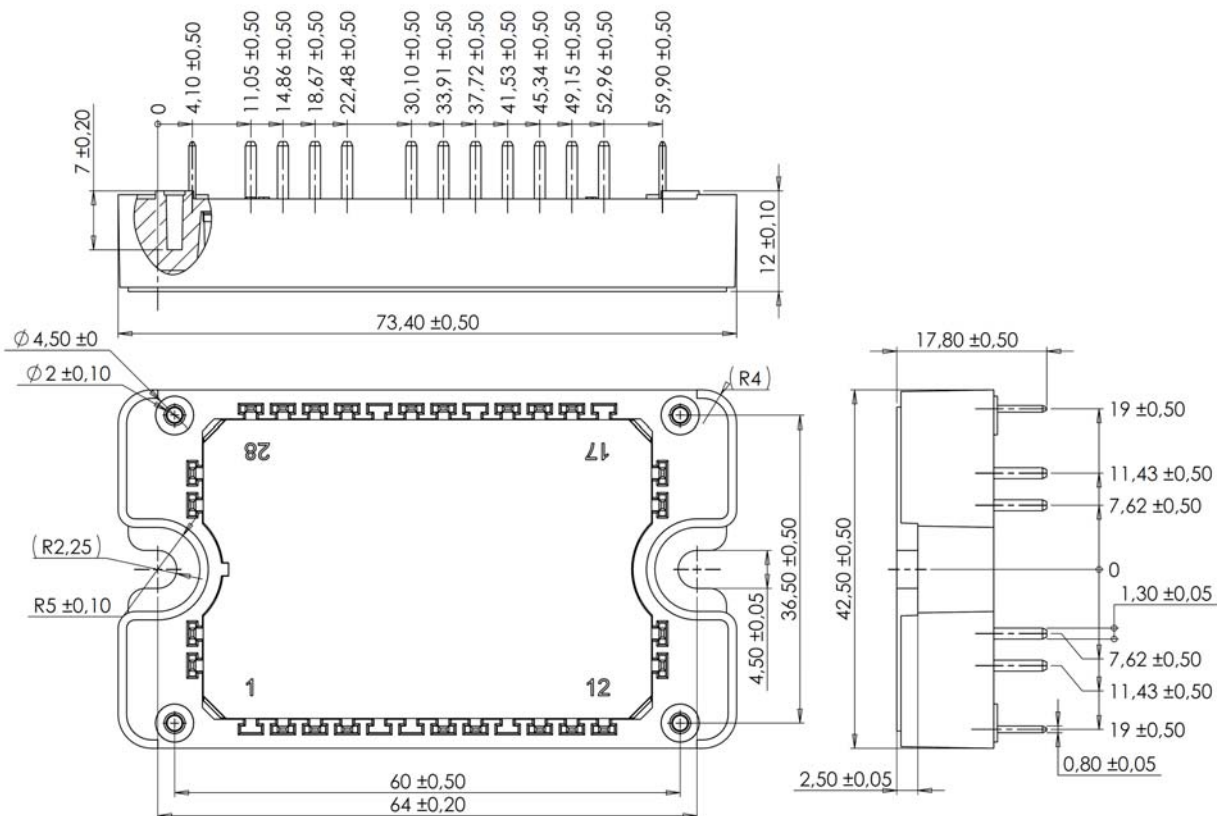
Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Typ	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
ΔR ₂₅ /R ₂₅			5		%
B _{25/85}	T ₂₅ = 298.15 K		3952		K
ΔB/B	T _C = 100°C		4		%

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]}$$

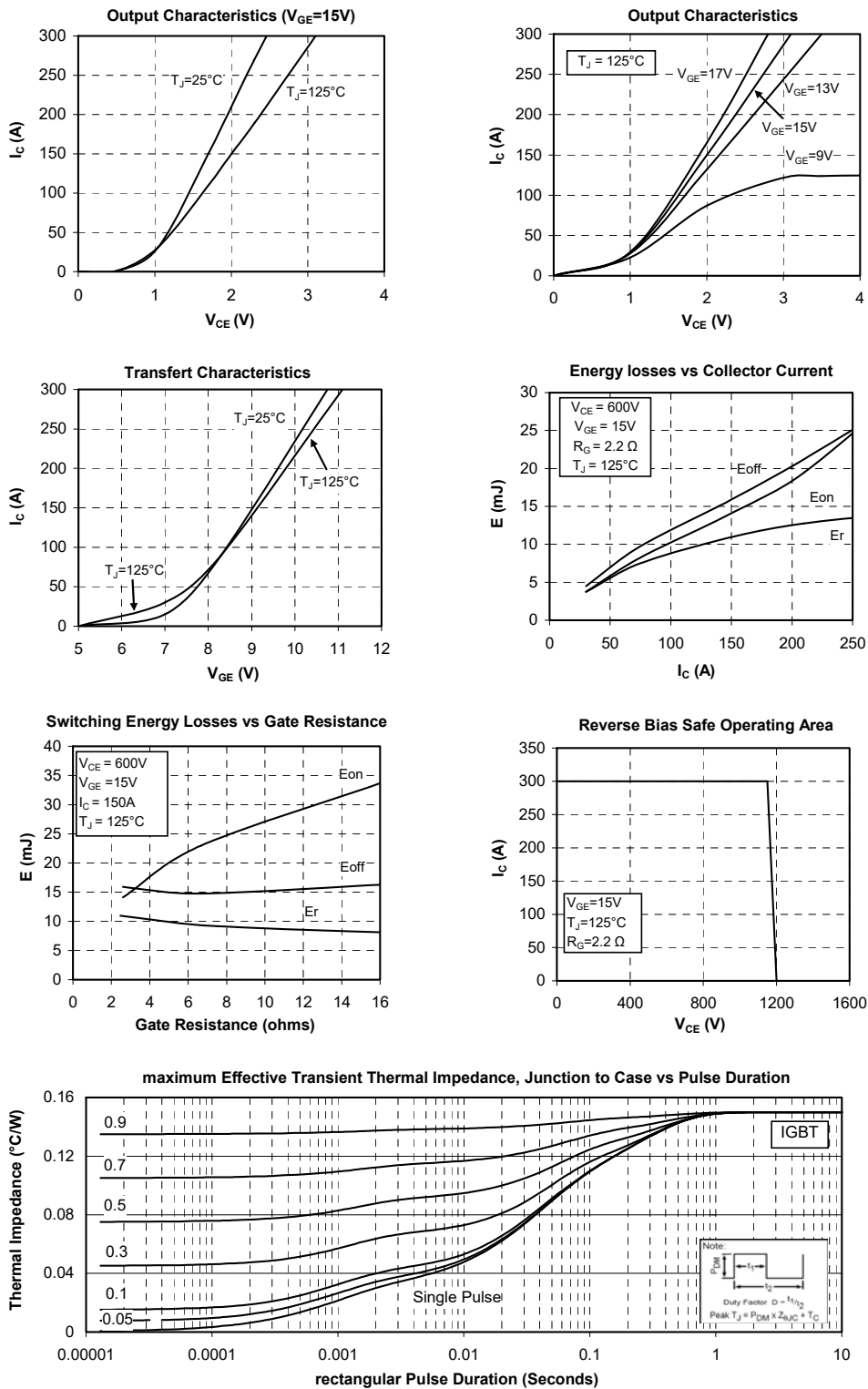
T: Thermistor temperature
 R_T: Thermistor value at T

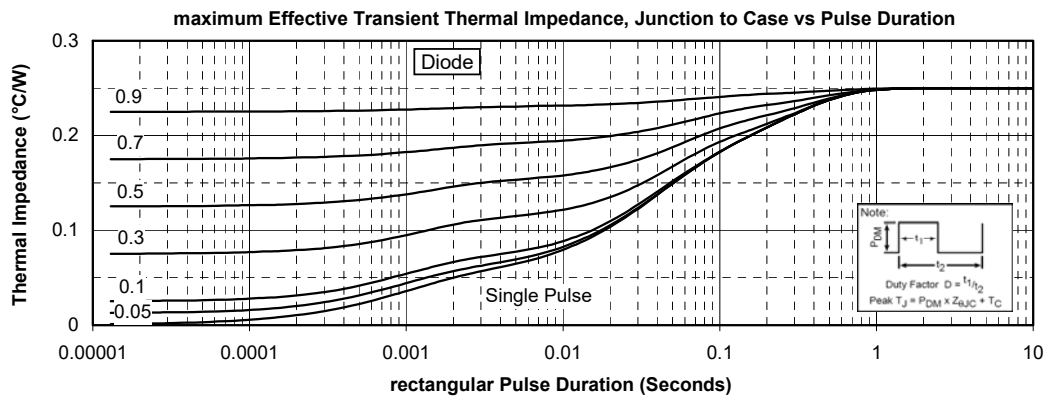
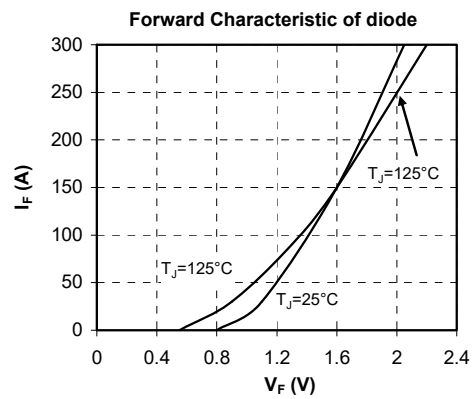
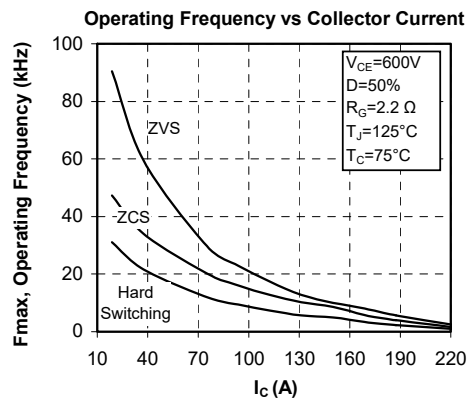
Package outline (dimensions in mm)



See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

Typical Performance Curve





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